## 45W USB C Charger



#### ■ Features:

- Miniaturized Design: Small size and light weight
- $\cdot$  No-load consumption<0.1W, Meet DOE VI
- Support protocols: PD&PPS, QC, FCP, SCP
- $\cdot \mbox{ Protections:}$  Short circuit / Overload
- / Overvoltage / OverTemperature
- $\cdot$  RoHS. Reach compliance

#### Application:

- $\cdot$  Mobile Phone
- Tablet
- Digital Product (USB-C Charge)

#### Description:

The FC045X series model is a USB C charger with a plastic shell design, which can effectively prevent users from electrical hazards. Its efficiency meets the latest energy efficiency requirements. It can work safely and effectively at an ambient temperature of 0°C to 40°C. It has complete Protection function and compliance with electronic information & audio and video (IEC60950, IEC60065, IEC62368) related certifications, compatible with PD&PPS, QC, FCP, SCP and other protocols, enabling quick charging of mobile phones and tablet products.

#### Key Specification

mey op	correction		
Model		FC045P01-200023C	
Output	Voltage	5V3A/9V3A/12V3A/15V3A/20V2.25A	
	Protocol	PD3. 0/PPS/FCP/SCP/QC2. 0/QC3. 0	
	Ripple&Noise(pk-pk)	200mVp-p	
Input	Voltage range	90 ~ 264VAC	
	Frequency range	47 ~ 63Hz	
	Efficiency(Typ.)	87.73%	
	Safety standards	IEC/EN60950、60065、62368	
		"●" Indicates that it is currently certified, "◎" Indicates that the applicant	
	Safety Type	meet the certification requirement but not be certified	
	СВ	0	
	CE+LVD	0	
Safety	BIS	<u> </u>	
	UL/CUL	<u> </u>	
	GS	<u> </u>	
	PSE	0	
	PSB	0	
		<u> </u>	
	RCM	0	
	BSMI	<u> </u>	
	IRAM	<u> </u>	
	КС	0	
	SABS	<u> </u>	
	SASO	<u> </u>	
	EAC	<u> </u>	
	B-MARK	<u> </u>	
	SII	0	
	BR	O	

# 45W USB C Charger

### **Electrical Specification**

Protocol         Protocol         Protocol           Start and Rise time         3000ms, 80ms/230VAC           Voltage         Protocol         Poslo,0/PFS/FCP/SCP/QC2.0/QC3.0           Ripple&Noise(pk-pk)         200Vp-p           Start and Rise time         3000ms, 80ms/230VAC           Voltage range         90 ~ 264VAC           Frequency range         47 ~ 63Hz           Standby Power         100m%           Efficiency(Typ.)         87.73%.           Input current(Typ.)         1.6A max @100°240Vac           Surge current(Typ.)         COLD START 60A/100Vac 100A/240Vac           Overvload         Protection Type: Turn off the output, through the PWM control chip built           VD overoltage         Protection Type: Turn off the output, through the PWM control chip built           VD overoltage         -20 ~ +75°C, 5 ~ 95% RH, non-condensing           Storage Temperature coefficiency         ±0.03%/C (0~ 50°C)           Vibration resistant         10 ~ 500Hz, 16 10min/circle, X, Y, Z 30mins for each           Altitude         2000m           Withstande voltage         I/P=0/P:100M Ohms / 500VDC / 25°C / 70% RH           EMI         Parameter         Standard           Radiated         EN5032(CISPR32), FCC Part 158         Class A           Voltage <t< th=""><th>Mode1</th><th>•</th><th></th><th></th><th></th></t<>	Mode1	•				
Protocol         PD3.0/PFS/PCP/SCF/QC2.0/QC3.0           Ripple&Noise(pk-pk)         200Wp-p           Start and Rise time         3000ns, 80ms/230VAC           Voltage range         90 ~ 264VAC           Frequency range         90 ~ 264VAC           Efficiency(Typ.)         87, 78%           Standby Power         100mW           Efficiency(Typ.)         87, 78%           Surge current(Typ.)         COLD START 60A/100Vac 100A/240Vac           Overload         140% max of rated output current           Recovers automically after fault condition is removed           Overvoltage         27Vmax           Overvoltage         Protocion Type: Turn off the output, through the PWM control chip built/ VDD voltage clemping           Operating Temperature         0- +40°C           Operating Iumidity         -20 ~ +75°C, 5 ~ 95% RH, non-condensing           Temperature coefficiency         ±0.03% /C (0-50°C)           Wintation resistant         1/P-0/P:100M Ohms / 500VDC / 25°C / 70% RH           Farameter         Standard         Test Level / Note           EMI         Radiated         EN50022(CISPR32), FCC Part 15B         Class B           Ittude         200om         Voltage         Class A         Voltage           Voltage         EN50032(CISPR32), FCC Pa						
Buttout         RippleMoise(pk-pk)         200Vp-p           Start and Rise time         300ms, 80ms/230VAC           Frequency range         90 ~ 264VAC           Frequency range         47 ~ 63Hz           Standby Power         100mW           Efficiency (Typ.)         87, 73%           Imput current (Typ.)         1.6A max @100^240Vac           Overload         140% max of rated output current           Overload         Recovers automatically after fault condition is removed           Overvoltage         Protectin Type: Turn off the output, through the PIM control chip built- VDD voltage clamping           Operating Temperature         0~ +40°C           Operating Humidity         -20 ~ +75°C, 5 ~ 95% RH, non-condensing           Storage Temperature coefficiency         ±0.03%/C (0~ 50°C)           Withstande voltage         1/P-0/P:38VAC           Isulation resistant         1/P-0/P:38VAC           BMI         Radiated         ENS002/CISPR32), FCC Part 158           EMI         Radiated         ENS1000-6-2           ENS         ENS1000-6-2         Class A           Function resistant         1/P-0/P:38VAC         Class A           Isulation resistant         1/P-0/P:38VAC         Class A           EMI         Radiated         E						
KippleKolse(pr.PK)         200/P-P           Start and Rise time         900 ~ 264VAC           Frequency range         90 ~ 264VAC           Frequency range         47 ~ 63Hz           Standby Poser         100m#           Efficiency(Typ.)         87.73%           Standby Poser         100m#           Efficiency(Typ.)         87.73%           Overload         Recovers automatically after fault condition is removed           Protect         0verload           Overvoltage         Protection Type: Turn off the output, through the PWM control chip built           VDD voltage clamping         Overvoltage to - 40°C           Overvoltage         0-40°C           Overvoltage         -20 ~ 475°C, 5 ~ 95% RH, non-condensing           Storage         -20 - 475°C, 5 ~ 95% RH, non-condensing           Temperature definitity         -20 - 475°C, 5 ~ 95% RH, non-condensing           Tistation resistant         1/P-0/P:100M Ohms / 500VDC / 25°C / 70% RH           Altitude         2000m           Isulation resistant         1/P-0/P:100M Ohms / 500VDC / 25°C / 70% RH           EMI         Parameter         Standard           Voltage         EN5000-4-2         Class B           Isulation resistant         1/P-0/P:100M Ohms / 500VDC / 25°C / 70% RH </td <td>011+011+</td> <td></td> <td colspan="3">PD3. 0/PPS/FCP/SCP/QC2. 0/QC3. 0</td>	011+011+		PD3. 0/PPS/FCP/SCP/QC2. 0/QC3. 0			
Woltage range Frequency range         90 ~ 264VAC 47 ~ 630z           Frequency range Frequency range Frequency range Frequency range Efficiency (Typ.)         87.73%.           Input current(Typ.)         87.73%.           Input current(Typ.)         1.6A max @100^240Vac           Surge current(Typ.)         1.6A max @100^240Vac           Overload         140% max of rated output current Recovers automatically after fault condition is removed           Overload         27Vmax           Overvoltage         Protection Type: Turn off the output, through the PWM control chip built VDD voltage clamping           Operating Temperature Operating Humidity         20 ~ 85% RH, non-condensing           Storage Temperature coefficiency         ±0.03%/C (0~50°C)           Wibstande voltage         1/P=0/P:38VAC           Itude         2000m           Withstande voltage         1/P=0/P:38VAC           Isulation resistant         10 ~ 855032(CISPR32), FCC Part 15B           EMI         Radiated         EN55032(CISPR32), FCC Part 15B           EMS         ES01000-4-2         Level 3, criteria A           EVIC         Parameter         Standard         Test Level /Note           EMI         Radiated         EN50000-4-2         Level 3, criteria A           EWI         Radiated         EN61000-4-3         L	output	Ripple&Noise(pk-pk)				
Image: Frequency range         47 ~ 63Hz           Standby Power         100mW           Standby Power         100mW           Input current(Typ.)         1. 6A max @100^240Vac           Input current(Typ.)         1. 6A max @100^240Vac           Surge current(Typ.)         1. 6A max @100^240Vac           Verload         Recovers automatically after fault condition is removed           Overload         Protection Type: Turn off the output, through the PWM control chip built           Overvoltage         0~40°C           Operating Humidity         20 ~ 85% RH, non-condensing           Storage         5.00 Mz/C (0~50°C)           Temperature&Humidity         -20 ~ 45°C, 5 ~ 95% RH, non-condensing           Totrage         10 ~ 500 Mz/C (0~50°C)           Withstand voltage         1/P=0/P:100M Ohms / 500 VDC / 25°C / 70% RH           Parameter         Standard         Test Level / Note           Conducted         ENS5032 (CISPR32), FCC Part 15B         Class B           Barnonic         EN61000-3-3            Parameter         Standard         Test Level / Note           EMS         ENS1000-4-2         100 KV cortesta           Radiated         EN61000-4-3         100KV cortesta           EMS         EN61000-4-5 <t< td=""><td></td><td>Start and Rise time</td><td colspan="3">3000ms, 80ms/230VAC</td></t<>		Start and Rise time	3000ms, 80ms/230VAC			
Standby Power         1000W           Efficiency (Typ.)         87.73%           Burge current (Typ.)         COLD START 60//100Vac 100A/240Vac           Surge current (Typ.)         COLD START 60//100Vac 100A/240Vac           OverLoad         Recovers automatically after fault condition is removed           Overload         Protection Type: Turn off the output, through the PWM control chip built- VDD voltage clamping           Operating Temperature         0 - 400°C           Operating Humidity         20 ~ 85% RH, non-condensing           Storage TemperatureAlumidity         -20 - 475°C, 5 ~ 95% RH, non-condensing           Temperature coefficiency Vibration resistant         10 ~ 500Hz, 16 10min/circle, X, Y, Z 30mins for each           Altitude         2000m           Withstande voltage         I/P=0/P:180M Ohms / 500VDC / 25°C / 70% RH           Parameter         Standard         Test Level / Note           EMI         Radiated         EN5032(CISPR22), FCC Part 15B         Class B           Harmonic         EN61000-3-2         Class A         Voltage           Voltage         Parameter         Standard         Test Level /Note           EMI         EN5032(CISPR22), FCC Part 15B         Class B         Enstandard           Radiated         EN5032(CISPR23), FCC Part 15B         Class A         Su		Voltage range	90 ~ 264VAC			
mA         Efficiency(Typ.)         87.73%           Input current(Typ.)         1.64 max 6100°240Vac           Surge current(Typ.)         COLD START 60A/100Vac 100A/240Vac           Overload         140% max of rated output current           Recovers automatically after fault condition is removed         27Vmax           Overvoltage         Protection Type: Turn off the output, through the PWM control chip built- VDD voltage clamping           Operating Humidity         20 ~ 85% RH, non-condensing           Storage         -20 ~ +75°C, 5 ~ 95% RH, non-condensing           TemperatureRMumidity         20 ~ 85% RH, non-condensing           Temperature coefficiency         ±0.03%/C (0~ 50°C)           Yibration resistant         10 ~ 500Hz, 16 10min/circle, X, Y, Z 30mins for each           Altitude         2000m           Withstande voltage         1/P=0/P:18WAC           Isulation resistant         1/P=0/P:18WAC           EMI         Radiated         EN5032(CISPR32), FCC Part 15B         Class B           Harmonic         EN61000-3-2         Class A           Voltage         EN61000-4-2         Evel /Note           EMS         EN50325, EN61000-4-3         Level 3, criteria A           Storage         EN61000-4-4         Level 3, criteria A           Radiated <t< td=""><td rowspan="4">输入</td><td>Frequency range</td><td colspan="3">47 ~ 63Hz</td></t<>	输入	Frequency range	47 ~ 63Hz			
Encode (1)         One (1)         One (1)         Output current (1)         Output current (1)           Protect         Overload         10% max of rated output current         10% max of rated output current           Overload         Recovers automatically after fault condition is removed         27% max         10%           Overvoltage         Protection Type: Turn off the output, through the PWM control chip built- VDD voltage clamping         10%           Operating Temperature         0-+40°C         10%         10%           Operating Hunidity         20 - 85% RH, non-condensing         10%         10%           Temperature coefficiency         ±0.03%/°C (0~50°C)         10%         10%         10%           Withstande voltage         1/P-0/P:100M Ohms / 500VDC / 25°C / 70% RH         10%         10%         10%           BMI         EMI         Parameter         Standard         Test Level / Note           Conducted         ENS1022(CISPR32), FCC Part 15B         Class B         10%         10%           Bustonic         EN61000-3-2         Class A         10%         10%         10%           Voltage         EN61000-4-2         Evel 3, 15K air; Level         10%         10%         10%           Buston resistant         10%         EN61000-4-3         Leve		Standby Power	100mW			
Surge current(Typ.)         COLD START 60A/100Vac 100A/240Vac           Protect ion         OverLoad         140% max of rated output current Recovers automatically after fault condition is removed 27Wmax           Overvoltage         Protection Type: Turn off the output, through the PWW control chip built- VDD voltage clamping           Operating Temperature         0-+40°C           Operating Humidity         20 ~ 455°C, 5 ~ 95% RH, non-condensing           Storage Temperature coefficiency         ±0.03%/°C (0-50°C)           Vibration resistant         10 ~ 500Hz, IG 10min/circle, X, Y, Z 30mins for each           Altitude         2000m           Withstande voltage         1/P-0/P:100W Ohms / 500VDC / 25°C/ 70% RH           Isulation resistant         1/P-0/P:100W Ohms / 500VDC / 25°C/ 70% RH           EMI         Parameter         Standard           Radiated         EN55032(CISPR32), FCC Part 15B         Class B           Radiated         EN51000-3-2         Class A           Voltage         EN61000-4-2         EN61000-4-3           ENS         ESD         EN61000-4-2         EN61000-4-3           ENS         ESD         EN61000-4-3         Level 3, criteria A           Susceptibility         EN61000-4-6         Level 3, criteria A           Surge         EN61000-4-6         Level 3, criteria A<		Efficiency(Typ.)	87.73%			
OverLoad         140% max of rated output current Recovers automatically after fault condition is removed 27Vmax           Overvoltage         Protection Type: Turn off the output, through the PWM control chip built- VDD voltage clamping           Operating Temperature Temperature & 0 ~ +40°C         0 ~ +40°C           Operating Humidity         20 ~ 85% RH, non-condensing           Temperature & 0 ~ +40°C         - +40°C           Operating Temperature         0 ~ +40°C           Operating Temperature         0 ~ +75°C, 5 ~ 95% RH, non-condensing           Temperature&Mumidity         -20 ~ +75°C, 5 ~ 95% RH, non-condensing           Temperature coefficiency         ±0.03%/°C (0 ~ 50°C)           Withstande voltage         1/P-0/P:3KVAC           Isulation resistant         10 ~ 500Hz, 16 10min/circle, X, Y, Z 30mins for each           Altitude         2000m           Withstande voltage         1/P-0/P:3KVAC           Isulation resistant         10 ~ 500HD.           Tarmonic         EN55032(CISPR32), FCC Part 15B         Class B           Radiated         EN5000-3-3            EN55035, EN61000-4-2         Level 3, criteria A           Susceptibility         EN51000-4-3         Level 3, criteria A           ESD         EN61000-4-4         Level 3, criteria A           Susceptibility <td>Input current(Typ.)</td> <td>1.6A max <math>@100^{\sim}</math></td> <td>240Vac</td> <td></td>		Input current(Typ.)	1.6A max $@100^{\sim}$	240Vac		
OverLoad         140% max of rated output current Recovers automatically after fault condition is removed 27Vmax           Overvoltage         Protection Type: Turn off the output, through the PWM control chip built- VDD voltage clamping           Operating Temperature Temperature & 0 ~ +40°C         0 ~ +40°C           Operating Humidity         20 ~ 85% RH, non-condensing           Temperature & 0 ~ +40°C         - +40°C           Operating Temperature         0 ~ +40°C           Operating Temperature         0 ~ +75°C, 5 ~ 95% RH, non-condensing           Temperature&Mumidity         -20 ~ +75°C, 5 ~ 95% RH, non-condensing           Temperature coefficiency         ±0.03%/°C (0 ~ 50°C)           Withstande voltage         1/P-0/P:3KVAC           Isulation resistant         10 ~ 500Hz, 16 10min/circle, X, Y, Z 30mins for each           Altitude         2000m           Withstande voltage         1/P-0/P:3KVAC           Isulation resistant         10 ~ 500HD.           Tarmonic         EN55032(CISPR32), FCC Part 15B         Class B           Radiated         EN5000-3-3            EN55035, EN61000-4-2         Level 3, criteria A           Susceptibility         EN51000-4-3         Level 3, criteria A           ESD         EN61000-4-4         Level 3, criteria A           Susceptibility <td></td> <td>Surge current(Typ.)</td> <td>COLD START 60A</td> <td>/100Vac_100A/240Vac</td> <td></td>		Surge current(Typ.)	COLD START 60A	/100Vac_100A/240Vac		
OverLoad         Recovers automatically after fault condition is removed           Protection         0vervoltage         277max           Overvoltage         Protection Type: Turn off the output, through the PWM control chip built- VDD voltage clamping           Operating Temperature         0~+40°C           Operating Humidity         20 ~ 85% RH, non-condensing           Storage         -20 ~ +75°C, 5 ~ 95% RH, non-condensing           Temperature coefficiency         ±0.03%/°C (0~50°C)           Vibration resistant         10 ~ 500Hz, 1G 10min/circle, X, Y, Z 30mins for each           Altitude         2000m           Withstande voltage         1/P=0/P:3KVAC           Isulation resistant         1/P=0/P:3KVAC           EMI         Radiated         EN5032(CISPR32), FCC Part 15B         Class B           Radiated         EN5032(CISPR32), FCC Part 15B         Class B           Harmonic         EN61000-3-2         Class A           Voltage         EN61000-4-2         Level 3, 15KV air; Level           Susceptibility         EFT/Burest         EN61000-4-3         Level 3, criteria A           Susceptibility         EFT/Burest         EN61000-4-4         Level 3, criteria A           Susceptibility         EFT/Burest         EN61000-4-6         Level 4, criteria A						
Protect ion         27Vmax           Overvoltage         Protection Type: Turn off the output, through the PWM control chip built- VDD voltage clamping           Operating Temperature         0~+40°C           Operating Temperature         0~+40°C           Operating Temperature 0~+40°C         0           Temperature coefficiency         ±0.03%/°C (0~50°C)           Temperature coefficiency         ±0.03%/°C (0~50°C)           Vibration resistant         10 ~ 500Hz, 1G 10min/circle, X, Y, Z 30mins for each           Altitude         2000m           Withstande voltage         1/P-0/P:3KVAC           Isulation resistant         1/P-0/P:100M 0hms / 500VDC / 25°C / 70% RH           Parameter         Standard         Test Level / Note           Conducted         EN55032(CISPR32), FCC Part 15B         Class B           Harmonic         EN61000-3-3            Voltage         EN61000-4-2         Level 3, criteria A           Susceptibility         EFT/Burest         EN61000-4-3         Level 3, criteria A           Susceptibility         EFT/Burest         EN61000-4-6         Level 4, eriteria A           Susceptibility         EFT/Burest         EN61000-4-8         Level 4, criteria A           Susceptibility         EFT/Burest         EN61000-4-8		OverLoad	-			
ion Overvoltage Protection Type: Turn off the output, through the PWM control chip built- VDD voltage clamping Operating Temperature Operating Humidity 20 ~ 85% RH, non-condensing Temperature coefficiency 40.03%/C (0~50°C) Vibration resistant 10 ~ 500H2, 16 10min/circle, X, Y, Z 30mins for each Altitude 2000m Withstande voltage I/P-0/P:3KVAC Isulation resistant 1/P-0/P:3KVAC EMS EMI EMI EMI EMI EMI EMS	Protect			atically after fault condition	I IS Felloved	
Environ ment         Operating Temperature Operating Hunidity         20 ~ 470°C           Storage Temperature&Hunidity         -20 ~ 475°C, 5 ~ 95% RH, non-condensing         -20 ~ 475°C, 5 ~ 95% RH, non-condensing           Temperature coefficiency         ±0.03%/°C (0~ 50°C)         -20 ~ 475°C, 5 ~ 95% RH, non-condensing           Temperature coefficiency         ±0.03%/°C (0~ 50°C)         -20 ~ 475°C, 5 ~ 95% RH, non-condensing           Altitude         2000m         -20 ~ 475°C, 5 ~ 95% RH, non-condensing           Wibstaion resistant         10 ~ 500HZ, 16 lomin/circle, X, Y, Z 30mins for each           Altitude         2000m           Withstande voltage         1/P-0/P:3KVAC           Isulation resistant         1/P-0/P:3KVAC           Isulation resistant         1/P-0/P:100M 0hms / 500VDC / 25°C/ 70% RH           Parameter         Standard         Test Level / Note           Conducted         EN55032(CISPR32), FCC Part 15B         Class B           Radiated         EN50032(CISPR32), FCC Part 15B         Class A           Voltage         EN61000-3-3            EN5053, EN61000-6-2, EN61204-3            Fers/Burset         EN61000-4-3         Level 3, criteria A           Susceptibility         EFT/Burest         EN61000-4-4         Level 3, criteria A           Sur						
Environment         Operating Temperature         0~+40°C           Operating Humidity         20 ~ 85% RH, non-condensing         -20 ~ +75°C, 5 ~ 95% RH, non-condensing           Temperature&Humidity         -20 ~ +75°C, 5 ~ 95% RH, non-condensing         -20 ~ +75°C, 5 ~ 95% RH, non-condensing           Temperature coefficiency         ±0.03%/°C (0~ 50°C)         -20 ~ +75°C, 5 ~ 95% RH, non-condensing           Temperature coefficiency         ±0.03%/°C (0~ 50°C)         -2000m           Withstande voltage         1/P-0/P:3KVAC		Overvoltage			igh the PWM control chip built-in	
Environ         Operating Hunidity         20 ~ 85% RH, non-condensing           Storage Temperature&Hunidity         -20 ~ +75°C, 5 ~ 95% RH, non-condensing         -20 ~ +75°C, 5 ~ 95% RH, non-condensing           ment         Temperature coefficiency         ±0.03%/°C (0~ 50°C)         -20 ~ +75°C, 5 ~ 95% RH, non-condensing           Withstande voltage         1/P-0/P:100M Ohms / 500VDC / 25°C/ 70% RH         -20 ~ +75°C, 5 ~ 95% RH, non-condensing           Withstande voltage         1/P-0/P:100M Ohms / 500VDC / 25°C/ 70% RH         Test Level / Note           Standard         Test Level / Note         Conducted         EN55032(CISPR32), FCC Part 15B         Class B           EMT         Radiated         EN50032(CISPR32), FCC Part 15B         Class A            Harmonic         EN61000-3-2         Class A            Voltage         EN61000-4-2         Level 3, 15KV air; Level           BKV         ESD         EN61000-4-2         Level 3, criteria A           Susceptibility         EFT/Burest         EN61000-4-3         Level 3, criteria A           Susceptibility         EFT/Burest         EN61000-4-6         Level 3, criteria A           Magnetic Field         EN61000-4-6         Level 4, criteria A         Susceptibility			VDD voltage clamping			
Storage Temperature&Humidity         -20 ~ +75°C, 5 ~ 95% RH, non-condensing           Temperature@Humidity         ±0.03%/°C (0~ 50°C)           Vibration resistant         10 ~ 500Hz, 1G 10min/circle, X, Y, Z 30mins for each           Altitude         2000m           Withstande voltage         1/P-0/P:3KVAC           Isulation resistant         1/P-0/P:100M Ohms / 500VDC / 25°C/ 70% RH           Parameter         Standard         Test Level / Note           Conducted         EN55032(CISPR32), FCC Part 15B         Class B           Radiated         EN55032(CISPR32), FCC Part 15B         Class A           Voltage         EN61000-3-2         Class A           Voltage         EN61000-4-2         Level 3, 15KV air; Level           EMS         EN5035, EN61000-6-2, EN61204-3         Test Level /Note           ESD         EN61000-4-2         Level 3, criteria A           Susceptibility         EFT/Burest         EN61000-4-3         Level 3, criteria A           Susceptibility         EFT/Burest         EN61000-4-5         Level 4, 4KV/L-N, criteri           Conducted         EN61000-4-6         Level 3, criteria A         Susceptibility		Operating Temperature	0~ +40 °C			
Environ       Temperature&Humidity       -20 ~ +75°C, 5 ~ 95% RH, non-condensing         Temperature coefficiency       ±0.03%/°C (0~ 50°C)         Vibration resistant       10 ~ 500Hz, 1G 10min/circle, X, Y, Z 30mins for each         Altitude       2000m         Withstande voltage       1/P-0/P:3KVAC         Isulation resistant       1/P-0/P:100M 0hms / 500VDC / 25°C/ 70% RH         Isulation resistant       1/P-0/P:100M 0hms / 500VDC / 25°C/ 70% RH         EMI       Parameter       Standard         Radiated       EN55032(CISPR32), FCC Part 15B       Class B         Harmonic       EN61000-3-2       Class A         Voltage       EN61000-6-2, EN61204-3          Parameter       Standard       Test Level /Note         ESD       EN61000-4-2       Level 3, 15KV air; Level         Radiated       EN61000-4-2       Level 3, criteria A         Radiated       EN61000-4-3       Level 3, criteria A         Surge       EN61000-4-5       Level 4, 4KV/L-N, criteri         Conducted       EN61000-4-6       Level 3, criteria A         Magnetic Field       EN61000-4-8       Level 4, criteria A         Voltage Dips       and       >95% dip 0.5 periods, 30		Operating Humidity	20 ~ 85% RH, no	n-condensing		
Environ       Temperature coefficiency       ±0.03%/°C (0~50°C)         remet       Vibration resistant       10 ~ 500Hz, 16 10min/circle, X, Y, Z 30mins for each         Altitude       2000m         Withstande voltage       1/P-0/P:3KVAC         Isulation resistant       1/P-0/P:100M 0hms / 500VDC / 25°C/70% RH         Parameter       Standard       Test Level / Note         Conducted       EN55032(CISPR32), FCC Part 15B       Class B         Harmonic       EN61000-3-2       Class A         Voltage       EN61000-6-2, EN61204-3          Radiated       EN61000-4-2       Level 3, 15KV air; Level         BKV       EMS       EFT/Burest       EN61000-4-3       Level 3, criteria A         Susceptibility       EFT/Burest       EN61000-4-5       Level 4, 4KV/L-N, criteri         Conducted       EN61000-4-6       Level 3, criteria A       Magnetic Field         Magnetic Field       EN61000-4-8       Level 4, criteria A		Storage		0.5%		
ment       Temperature coefficiency       ±0.03%/C (0~50°C)         Vibration resistant       10 ~ 500Hz, 16 10min/circle, X, Y, Z 30mins for each         Altitude       2000m         Withstande voltage       1/P-0/P:3KVAC         Isulation resistant       1/P-0/P:100M 0hms / 500VDC / 25°C/ 70% RH         Parameter       Standard         Conducted       EN55032(CISPR32), FCC Part 15B         Class B       Radiated         Radiated       EN55032(CISPR32), FCC Part 15B         Class A       Voltage         Voltage       EN61000-3-2         Class A       Voltage         Voltage       EN61000-4-3         EMS       ESD         EMS       EFT/Burest         EMS       EFT/Burest         EMS       EN61000-4-5         Level 3, criteria A         Surge       EN61000-4-6         Level 3, criteria A         Surge       EN61000-4-6         Level 3, criteria A         Surge       EN61000-4-6         Voltage Dips       EN61000-4-8         Voltage Dips       EN61000-4-11         Adje 25 periods,       30		Temperature&Humidity	$-20 \sim +75$ °C, 5	~ 95% RH, non-condensing		
Ment       Vibration resistant       10 ~ 500Hz, 1G 10min/circle, X, Y, Z 30mins for each         Altitude       2000m         Withstande voltage       I/P-0/P:3KVAC         Isulation resistant       I/P-0/P:100M 0hms / 500VDC / 25°C/ 70% RH         Parameter       Standard       Test Level / Note         Conducted       EN55032 (CISPR32), FCC Part 15B       Class B         Radiated       EN55032 (CISPR32), FCC Part 15B       Class A         Voltage       EN61000-3-2       Class A         Voltage       EN61000-6-2, EN61204-3          Parameter       Standard       Test Level /Note         ESD       EN61000-4-2       Level 3, 15KV air; Level         8KV contact, criteria A       Susceptibility       Susceptibility         EFT/Burest       EN61000-4-5       Level 3, criteria A         Surge       EN61000-4-6       Level 3, criteria A         Voltage Dips       EN61000-4-8       Level 4, criteria A		Temperature coefficiency	±0.03%/°C (0~	50℃)		
Altitude2000mWithstande voltageI/P-O/P:3KVACIsulation resistantI/P-O/P:100M Ohms / 500VDC / 25°C/ 70% RHParameterStandardTest Level / NoteConductedEN55032(CISPR32), FCC Part 15BClass BRadiatedEN55032(CISPR32), FCC Part 15BClass AVoltageEN61000-3-2Class AVoltageEN61000-6-2, EN61204-3ParameterStandardTest Level /NoteESDEN61000-4-2Level 3, 15KV air; Level8KV contact, criteria ASusceptibilityEFT/BurestEN61000-4-3Level 3, criteria ASurgeEN61000-4-5Level 4, 4KV/L-N, criteriConductedEN61000-4-6Level 4, criteria ASurgeEN61000-4-8Level 4, criteria AVoltage DipsEN61000-4-11>95% dip 0.5 periods, 30dip 25 periods,andSurge periods, 30	ment				s for each	
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			0 1	EN61000-4-11	1 1 /	
interruptions >95% interruptions 250						
		Made	•		295% Interruptions 250	
$0 \text{ thers} \qquad \qquad$	Others			L-HDBK-217F (25°C)		
512e(W*H*D) 03*42.3*28mm	0.01101.0	51Ze((w+H+D) 03*42.3*28mm				
1. All specifications and parameters shall be measured at the input of 230VAC, rated load and ambient temperature of 25°C unless	Remark					
otherwise specified. 2. Ripple and noise measurement method: capacitance of 0.1uF and 47uF in parallel at the terminal and the measurement is performed						
under the 20MHZ handwidth						
Remark 3. Accuracy: includes setting error, linear adjustment rate and load adjustment rate.						
4. The power supply adapter is an independent component, but the final adapter still needs to be confirmed in connection with the						
		electromagnetic compatibility of the terminal equipment.				